

MH4D Development

Eric Meier

Plasma Science and Innovation Center
University of Washington



PSI-Center Meeting
August 13, 2007

Outline



- Summary of previous work
- New b.c. development
 - Non-parallel periodic boundaries
 - Operator matrix b.c.
- Atomic physics development
 - Spheromak simulations
- Other physics development
 - Variable resistivity, ohmic heating
- Benchmarking
 - Screw pinch instability
 - ZaP simulations
- Future work

Summary of previous work

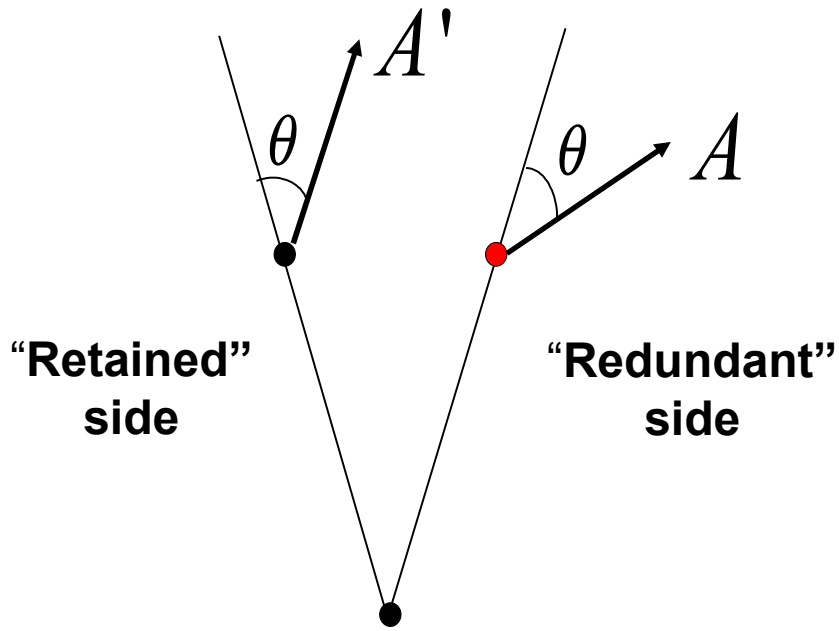
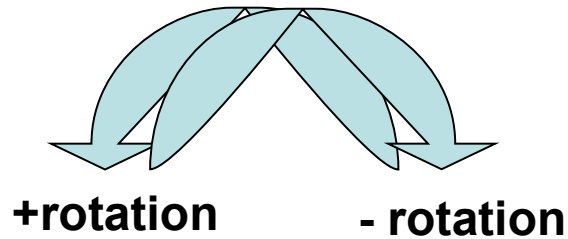
Previous Work

- Insulating b.c.
 - Apply magnetic field b.c.
 - Allow non-zero $E_{\text{tang.}}$; $E_{\text{normal}}=0$
 - Allow v_{normal} (density floor required)
- Periodic b.c.
 - Multi-directional
- Initial ZaP simulations

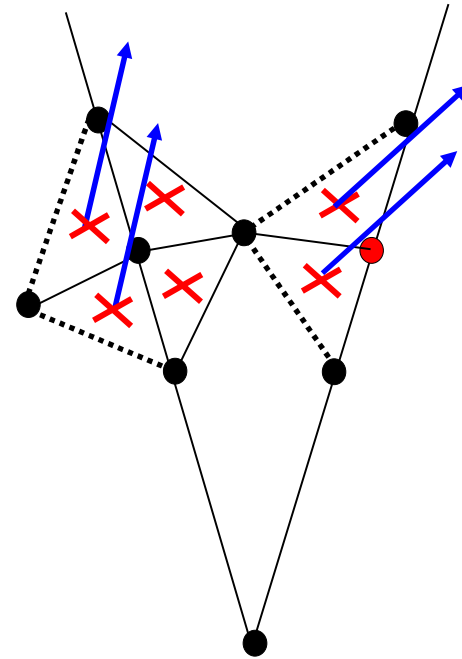
New boundary condition development

Non-parallel periodic b.c.

Rotation required across boundary



Curl computation uses vector information from surrounding tetrahedra



Non-parallel periodic b.c.

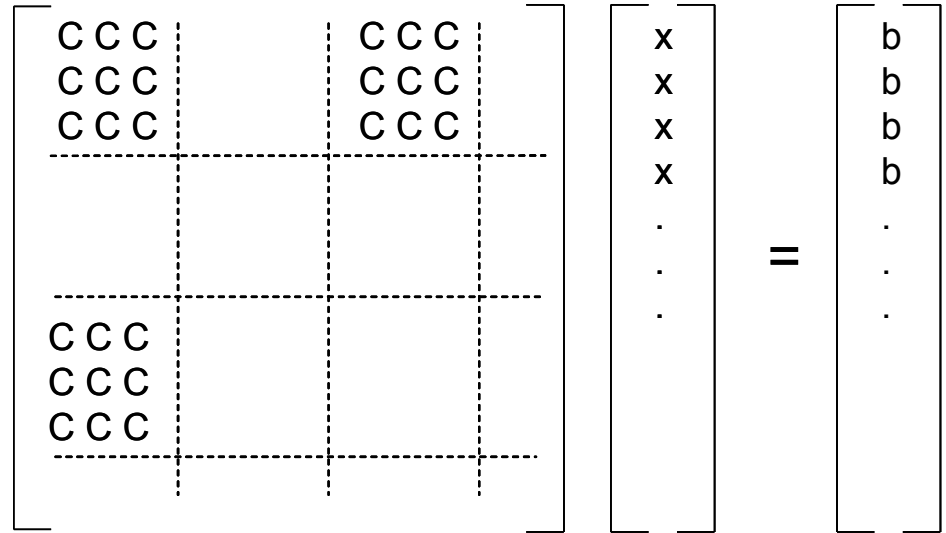
Operator matrices must be modified

Normally: $Cx = b$

For rotated vectors x' and b' :

$$CR^T x' = R^T b' \Rightarrow RCR^T x' = b'$$

$$\Rightarrow C' = RCR^T$$



For boundary rotation and periodic rotation:

$$CR_p^T R_b^T x' = R_p^T R_b^T b' \Rightarrow R_b R_p C R_b^T R_p^T x' = b'$$

$$\Rightarrow C' = R_b R_p C R_p^T R_b^T$$

Atomic physics development

Atomic Physics Development

- Phase I
 - Modify continuity equations
 - Assume constant neutral background density
 - Allow variable neutral background density
- Phase II
 - Modify momentum and energy equations

Atomic Physics Development Phase I



Temperature dependent ionization

$$\frac{\partial \rho_i}{\partial t} = -\nabla \cdot (\rho_i \mathbf{v}_i) + \Gamma_{ion} \frac{\text{kg}}{\text{m}^3} \text{s}^{-1}$$

$$\Gamma_i = \langle \sigma_{ion} \mathbf{v}_e \rangle \rho_i n_n$$

$$\text{Use } \langle \sigma_{ion} \mathbf{v}_e \rangle = \frac{2 \times 10^{-13}}{6.0 + T_{e,eV} / 13.6} \left(\frac{T_{e,eV}}{13.6} \right)^{1/2} \exp\left(-\frac{13.6}{T_{e,eV}} \right) \text{m}^3 \text{s}^{-1}$$

(ref. Goldston, Rutherford, Intro. to Plasma Physics, 1995, p. 151)

$$\text{If } \mathbf{v}_i=0, \text{ analytically: } \rho_i = \rho_{i,0} \exp(\langle \sigma_{ion} \mathbf{v}_e \rangle n_n t_{total})$$

Atomic Physics Development Phase I



Temperature dependent recombination

$$\frac{\partial \rho_i}{\partial t} = -\nabla \cdot (\rho_i \mathbf{v}_e) - \Gamma_{rec}$$

$$\begin{aligned}\Gamma_{rec} &= \langle \sigma_{rec} \mathbf{v}_e \rangle \rho_i n_i \\ &= \langle \sigma_{rec} \mathbf{v}_e \rangle \rho_i^2 \frac{1}{1.67 \times 10^{-27}}\end{aligned}$$

Use approximation: $\langle \sigma \mathbf{v}_e \rangle = 0.7 \times 10^{-19} \left(\frac{13.6}{T_{e,eV}} \right)^{1/2} \text{ m}^3 \text{ s}^{-1}$

(ref. Goldston, Rutherford, Intro. to Plasma Physics, 1995, p. 152)

If $\mathbf{v}_i=0$, analytically:
$$\rho_i = \frac{1}{t_{total} \langle \sigma_{rec} \mathbf{v}_e \rangle \frac{1}{1.67 \times 10^{-27}} + \frac{1}{\rho_0}}$$

Atomic Physics Development Phase I



Track neutral fluid density

Assuming $\mathbf{v}=0$,

$$\frac{\partial \rho_n}{\partial t} = -\Gamma_{ion} + \Gamma_{rec} ; \quad \frac{\partial \rho_i}{\partial t} = \Gamma_{ion} - \Gamma_{rec}$$

Compute Γ_{ion} and Γ_{rec} in each cell. Must not violate simple accounting!

- if $\Gamma_{ion} dt$ is greater than ρ_{ion} , $\rho_{ion} = \rho_{ion} + \rho_n$; $\rho_n = 0$
- if $\Gamma_{rec} dt$ is greater than $\rho_i - \rho_{i,floor}$, $\rho_n = \rho_n + (\rho_i - \rho_{i,floor})$;
 $\rho_i = \rho_{i,floor}$

Atomic Physics Development Phase I



Comments

- MH4D gives precisely the expected analytical solutions for simple problems.
- In coronal equilibrium, MH4D predicts the expected $\sim 50\%$ ionization at 1.5 eV.
- Predicts the expected $\sim 100\%$ ionization at 13.6 eV.

Atomic Physics Development Phase II



Single-fluid plasma model

- Cold neutral fluid with initial distribution
- Assume $\mathbf{v}_n = \mathbf{0}$

$$\frac{\partial \rho_i}{\partial t} = -\nabla \cdot (\rho_i \mathbf{v}_i) + \Gamma_{ion} - \Gamma_{rec}$$

$$\frac{\partial \rho_n}{\partial t} = -\Gamma_{ion} + \Gamma_{rec}$$

$$\rho_i \frac{\partial \mathbf{v}_i}{\partial t} + \nabla(p_e + p_i) = \mathbf{j} \times \mathbf{B} - (\Gamma_{rec} + \Gamma_{cx}) m_i \mathbf{v}_i$$

$$\frac{\partial p}{\partial t} + \mathbf{v} \cdot \nabla p = -\gamma p \nabla \cdot \mathbf{v} + (\gamma - 1) \eta \mathbf{j}^2 - (\gamma - 1) (\Gamma_{ion} + \Gamma_{cx}) m_n \Phi_{ion} \\ - (\Gamma_{rec} + \Gamma_{cx}) m_i p$$

Atomic Physics Development Phase II



- Spheromak tilt problem
 - “Tuna can” flux conserver
 - $L/R=2.5$
 - $\text{Beta}=2.5\%$
 - Flat pressure profile
 - Force-free i.c. $\rightarrow \mathbf{B}$
 - Find \mathbf{A} that satisfies $\text{curl}(\mathbf{A})=\mathbf{B}$
 - Allow $\mathbf{A}_{\text{tangential}}$ on boundaries, but $d/dt(A_{\text{tang.}})=0$.
 - Find tilt growth rate with and without atomic physics

Atomic Physics Development Phase II

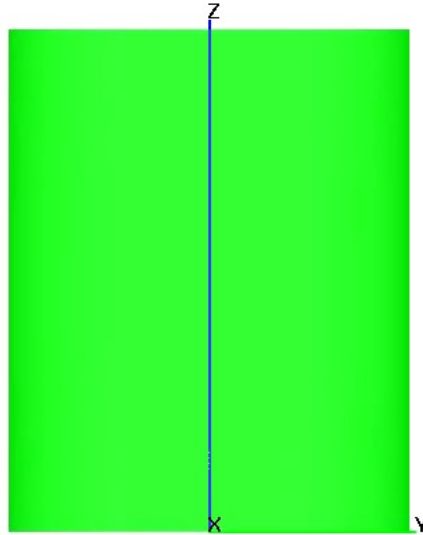
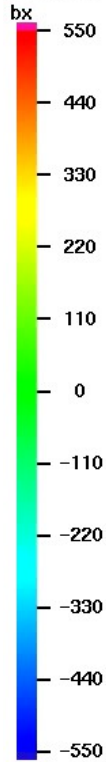


Movie

0

0.000000e+00

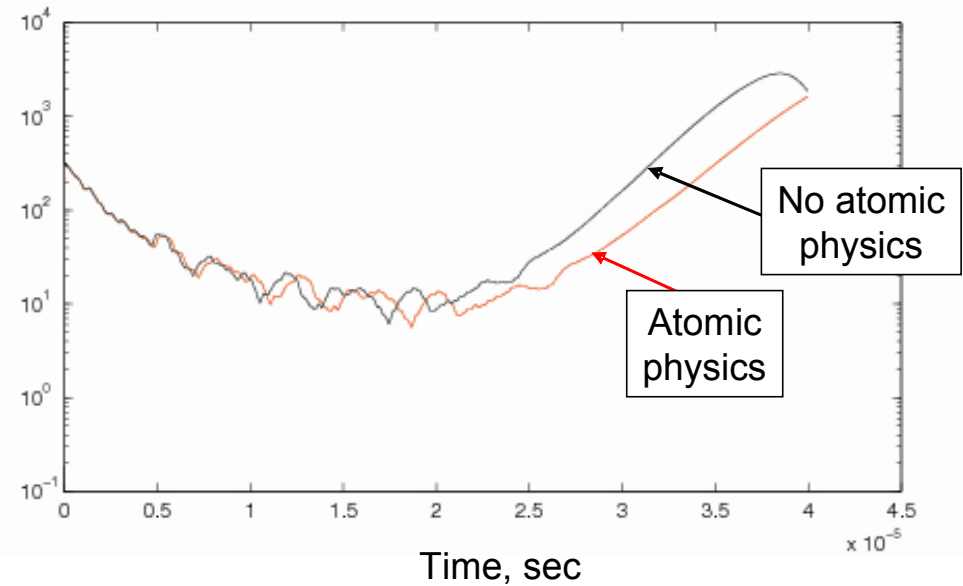
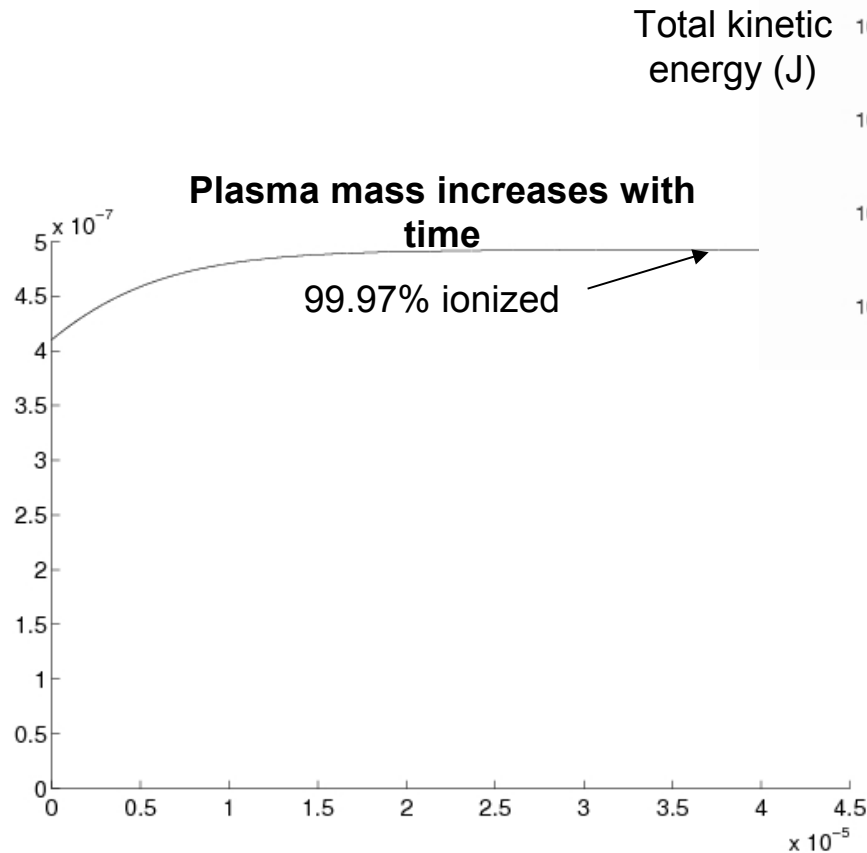
Cutplane



Atomic Physics Development Phase II



K.E. growth with and without atomic physics



Tilt growth rate is 14.0%
less with atomic physics.

$$\gamma\tau_A = 0.047 \text{ vs. } \gamma\tau_A = 0.055$$

Other physics development

Variable resistivity, Ohmic heating

- Chodura (anomalous) resistivity:

$$\eta_c = v_c \frac{m_e}{ne^2}, \quad v_c = C_c \omega_{pi} \left[1 - \exp\left(-\frac{v_e}{fv_s}\right) \right], \quad v_e = \frac{j}{ne}, \quad v_s = \sqrt{\frac{\gamma p}{\rho}}$$

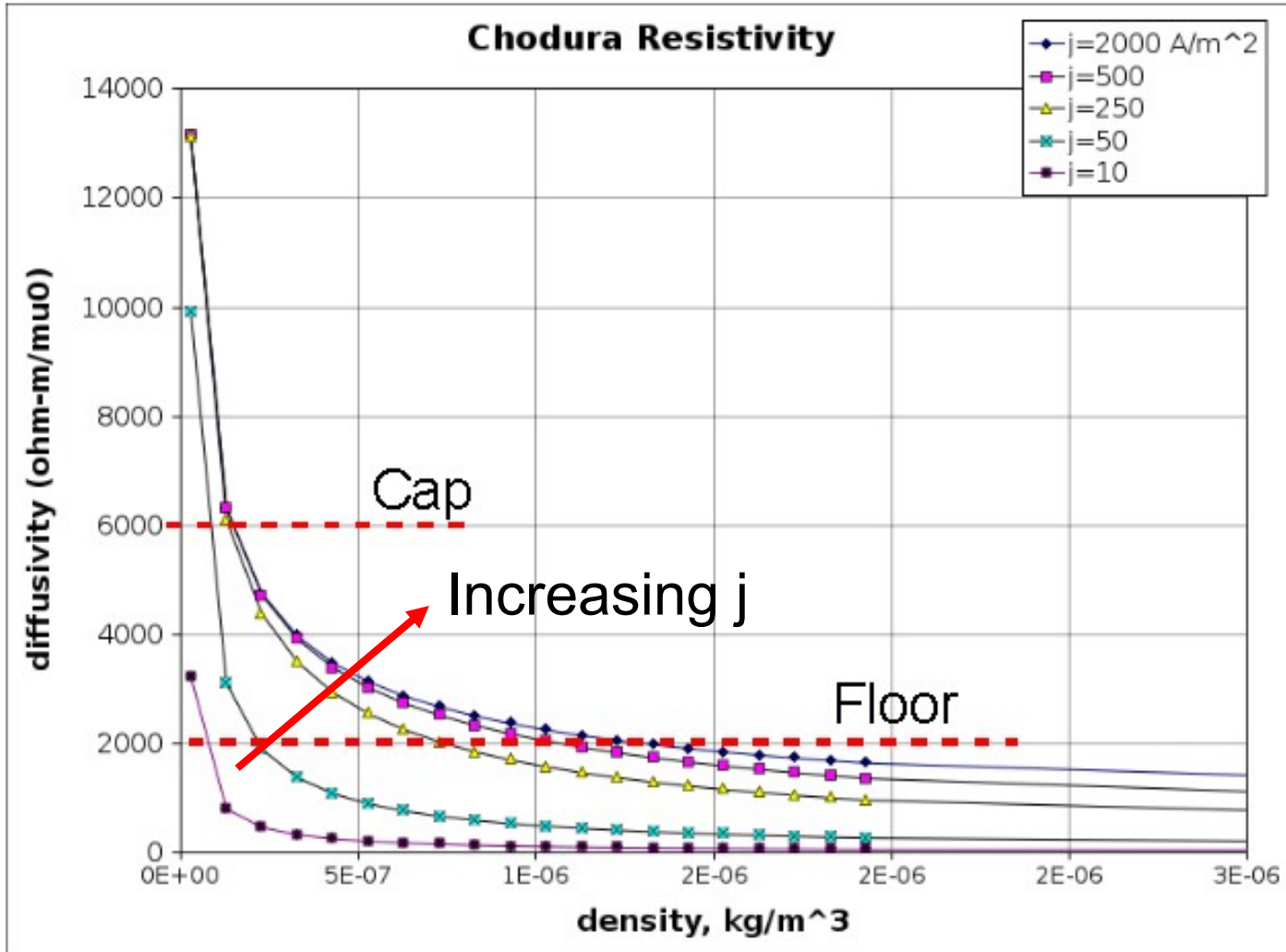
$$C_c \approx 1, f \approx 3$$

- Spitzer resistivity: $\eta_{Sp.} = \frac{(5 \times 10^{-5}) \ln \Lambda}{T_{eV}^{\frac{3}{2}}}$

- Explicit timestep limit: $2 \frac{\eta}{\mu_0} \frac{\Delta t}{\Delta x^2} < 1$

- Ohmic heating: $\frac{\partial p}{\partial t} + \mathbf{v} \cdot \nabla p = -\gamma p \nabla \cdot \mathbf{v} + (\gamma - 1) \eta \mathbf{j}^2$

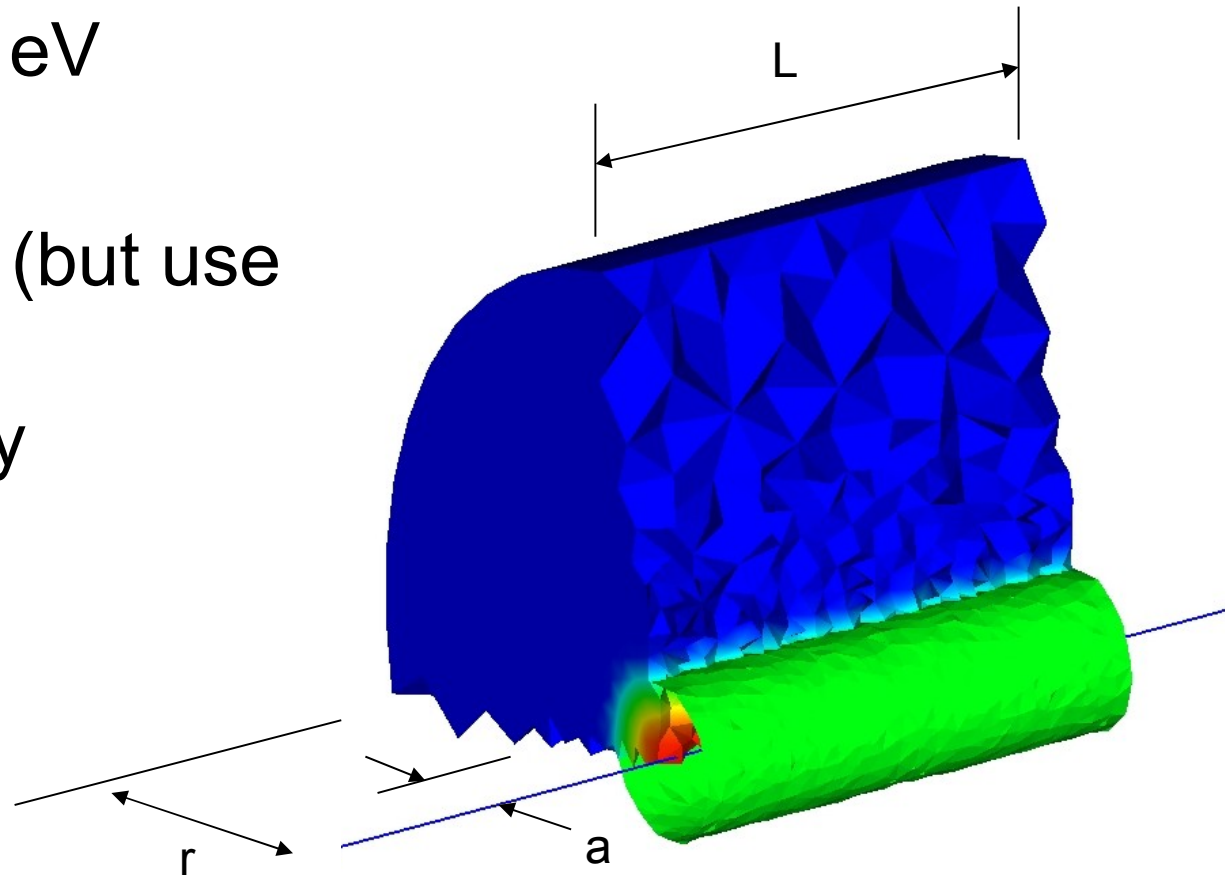
Chodura resistivity



Benchmarking

Screw pinch benchmark

- Parabolic pressure profile
- $T = \text{const.} = 100 \text{ eV}$
- $B_z = \text{const.}$
- Density $\sim p/kT$ (but use density floor)
- Helical velocity perturbation

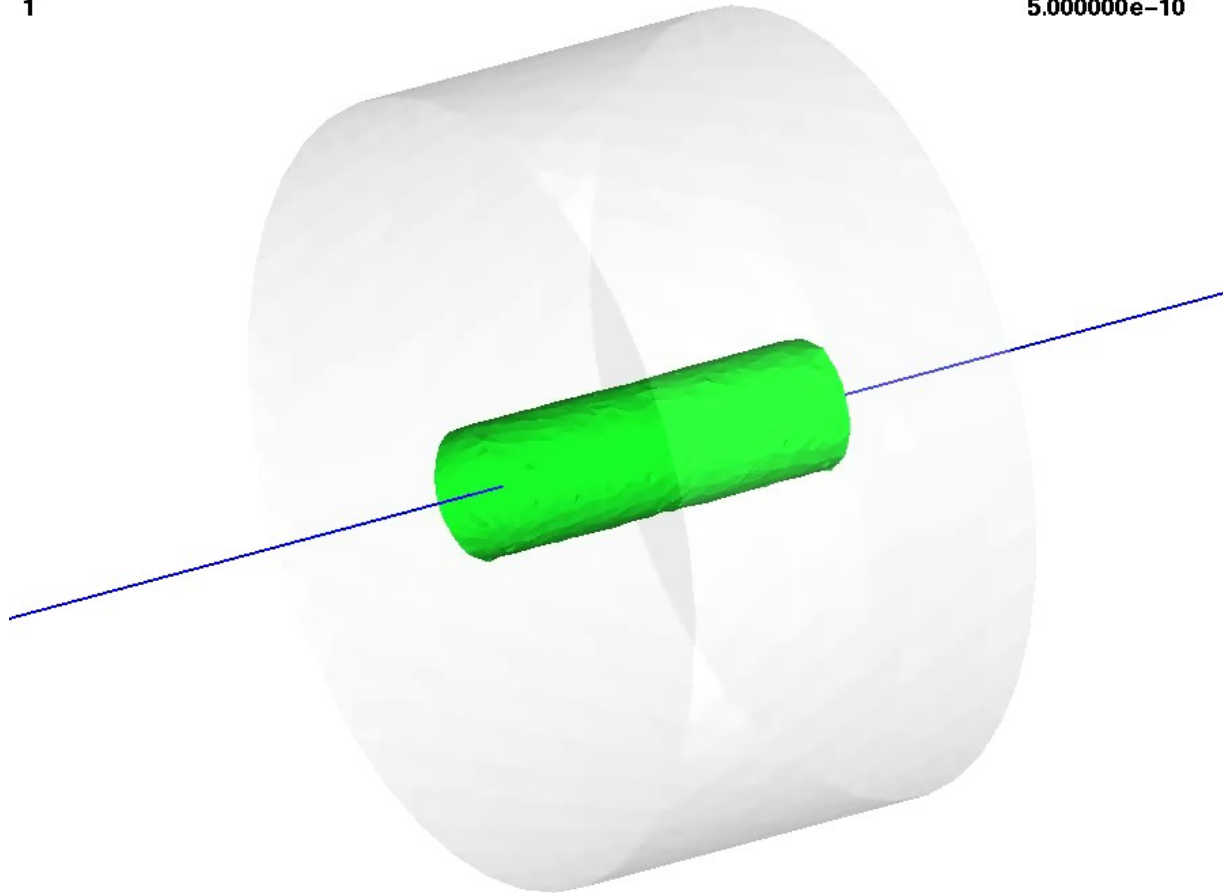


Screw pinch benchmark, cont.'d

Movie

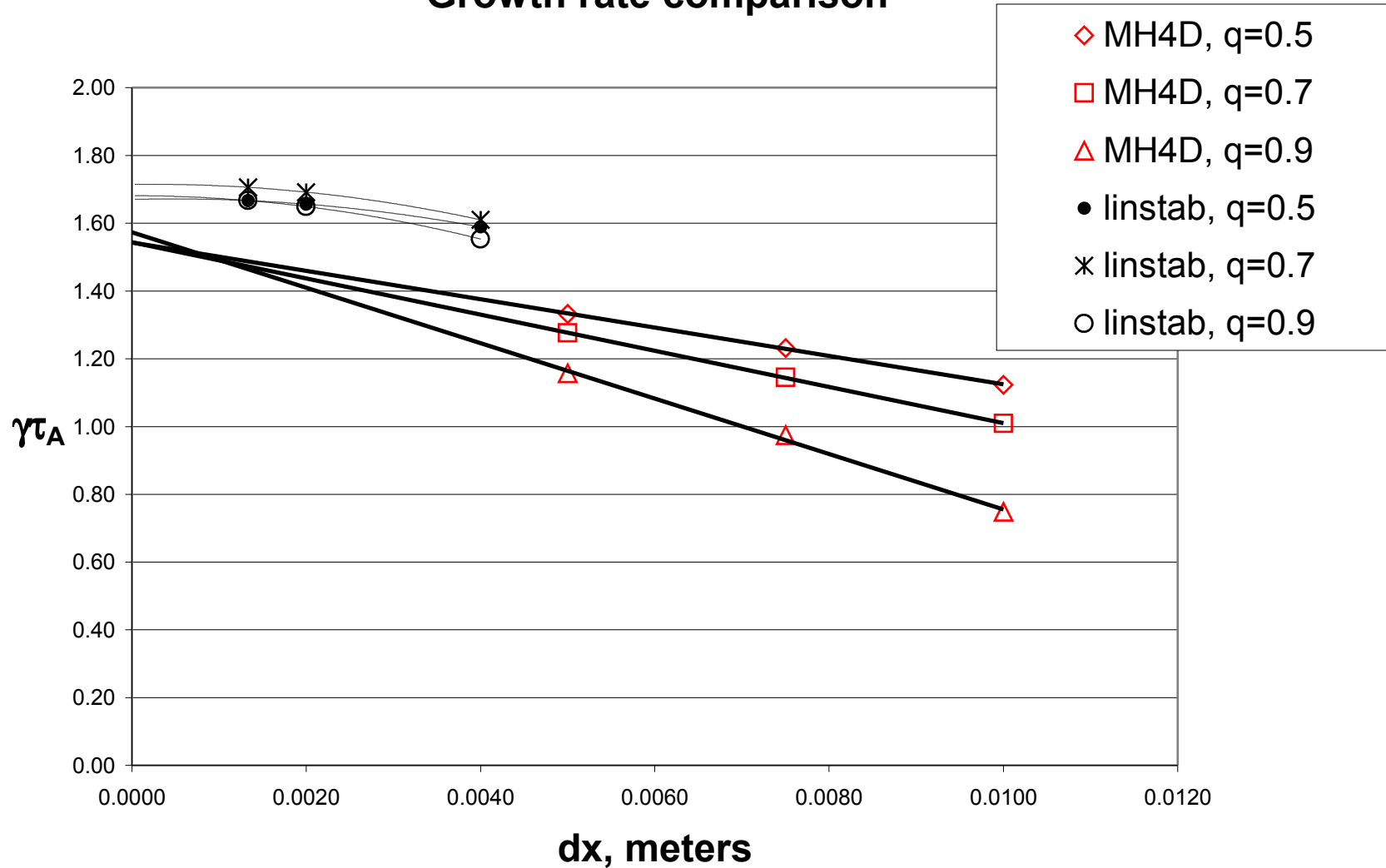
1

5.000000e-10



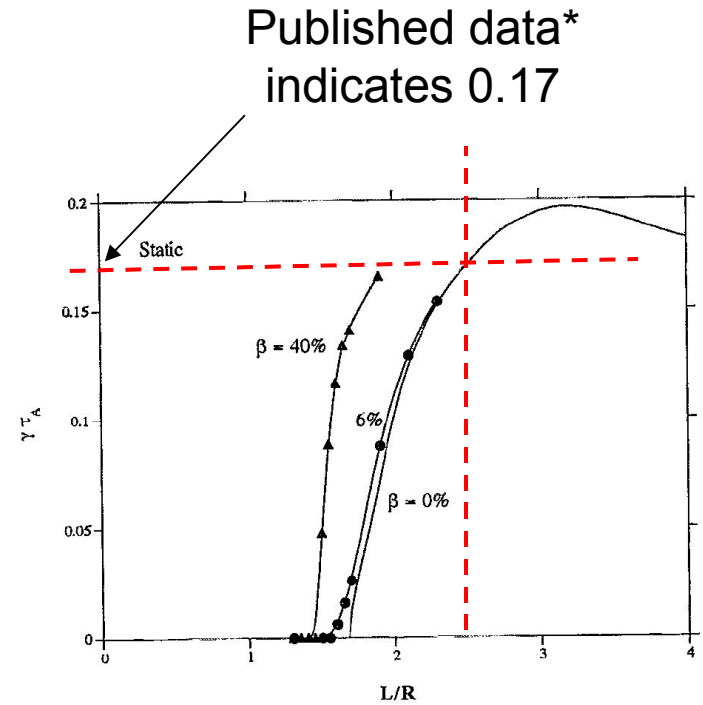
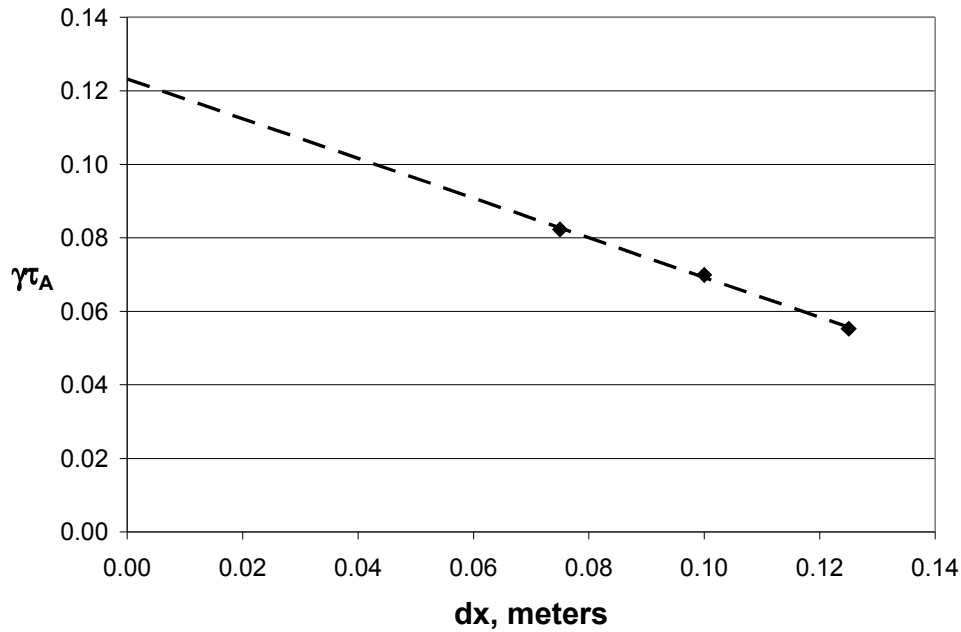
Screw pinch benchmark

Growth rate comparison



Spheromak benchmark

MH4D tilt growth rates



* Shumlak, Fowler, Morse, Phys. Plasmas, Vol. 1, No. 3, March 1994

Comparison to MACH2 via ZaP simulations



- Work in progress
- Resolution unlikely to approach MACH2
- Interplay of several factors is complicating matters:
 - Significant resistivity range is needed
 - High resolution is necessary
 - Low density floor would be ideal to capture low density current paths in plasma

Future work

Future work

- To finish MS:
 - Implement implicit and semi-implicit methods for high resolution sim's?
 - Atomic physics in ZaP
 - Significant time available on Bassi
- PhD work:
 - To be discussed shortly by Dr. Shumlak